

PrimePower Cell EM(ElectroMigration) Analysis on Advanced Process

MH.Tsai, Joe.Chueh
Global Unichip Corporation

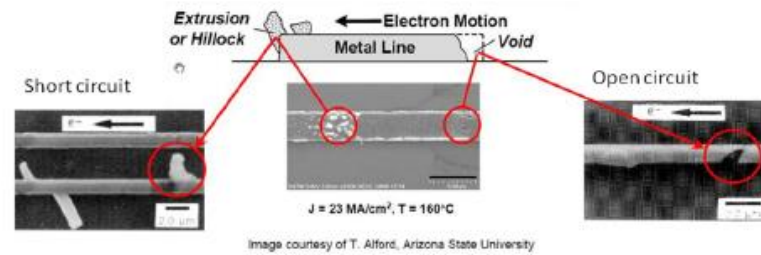
Agenda

- **Cell EM Introduction**
- **Cell EM Trend?**
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- **Experiment Result**
- **N7/N6/N5/N3 Cases Sharing**
- **Summary**

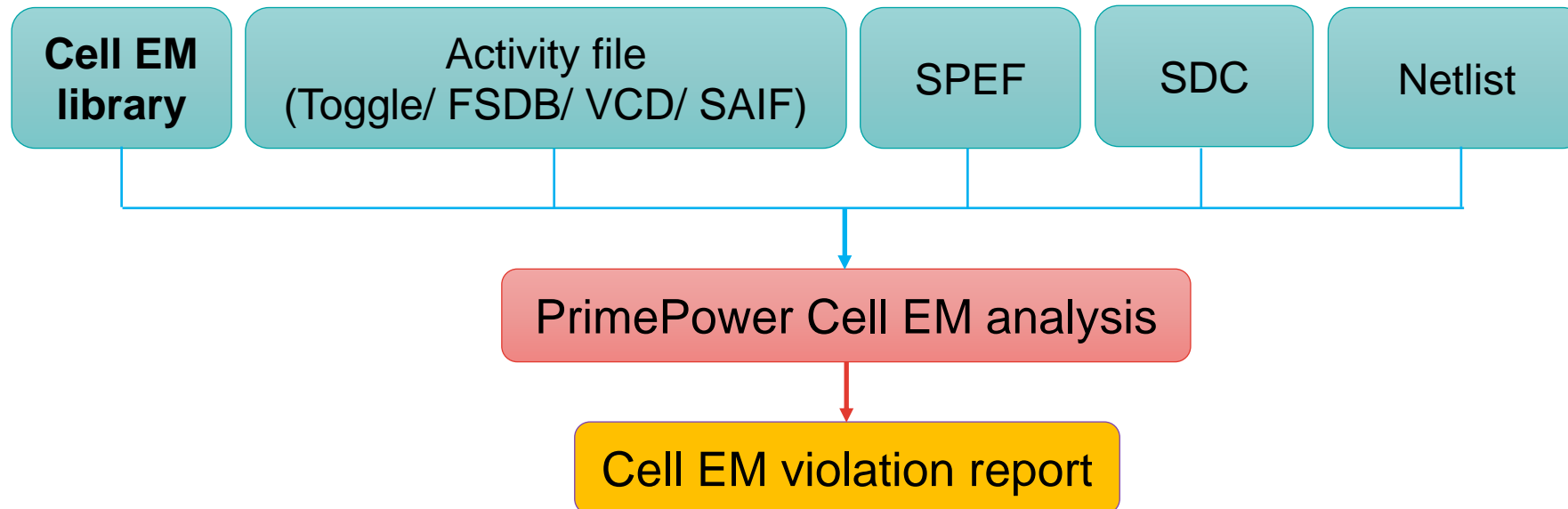
Agenda

- **Cell EM Introduction**
- **Cell EM Trend?**
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- **Experiment Result**
- **N7/N6/N5/N3 Cases Sharing**
- **Summary**

Introduction



- EM(ElectroMigration)
 - Current density through the conductor is high enough to cause the drift of metal ions.
- PrimePower Cell EM analysis flow



Introduction – Cell EM library

- Cell EM library includes three current type table
 - Average / RMS / Peak current table (represent by toggle rate)
- EM library example:

Maximum toggle rates indexed by input transition time and output capacitance

```
em_lut_template(em_template_3x3) {
  variable_1 : input_transition_time;
  index_1("0, 1, 2");
  variable_2 : total_output_net_capacitance;
  index_2("0, 1, 2"); }
electromigration () {
  related_pin : "i0";
  current_type: average | rms | peak ;
  em_max_toggle_rate (em_template_3x3)
  {
    index_1 ("0.002, 0.004, 0.008");
    index_2 ("0.0001, 0.0536, 0.0132");
    values ( \
      "2093.356, 390.168, 156.066," \
      "2093.356, 390.168, 156.066," \
      "2093.356, 390.168, 156.066," \
    ); }
}
```

Electromigration tables can be provided for different current types which correspond to different EM issues

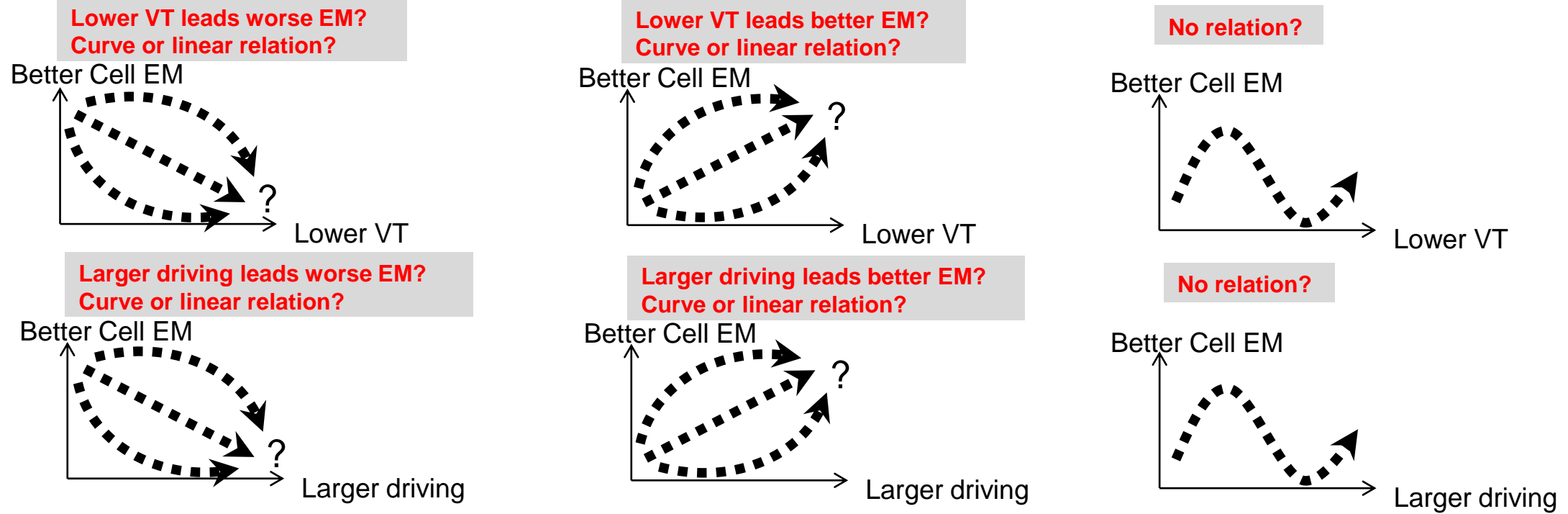
Current Type	EM Issue
Average	Self healing in AC
RMS	Joule Heating
Peak	Reliability

Agenda

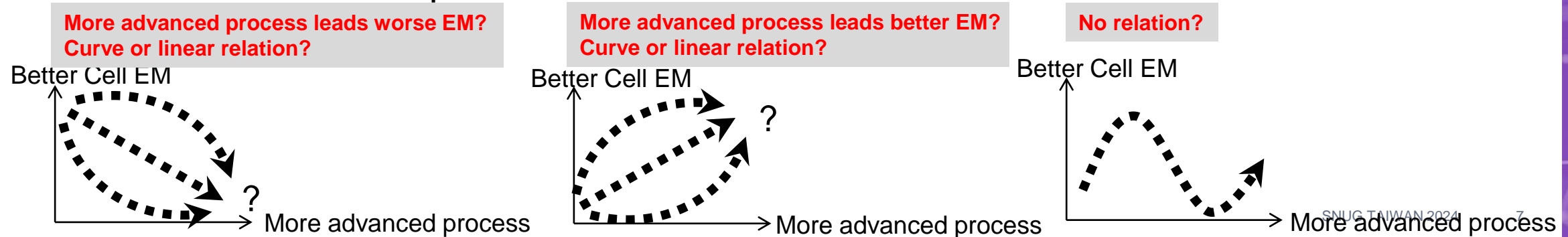
- Cell EM Introduction
- **Cell EM Trend?**
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- Experiment Result
- N7/N6/N5/N3 Cases Sharing
- Summary

Cell EM Trend? – Analyze by Cell EM Library

- What's cell type & driving have worse EM ?



- Whether more advanced process with worse EM ?



Cell EM Trend? – Analyze by Real Case

- **When should we run the PrimePower Cell EM analysis?**
 - Run for every version of Post-APR netlist?
 - Run after fixing max_cap / max_tran ?
- **What's the scale number of Cell EM violations?**
 - Dozens? Hundreds? Thousands? Tens of thousands?
- **When should we fix the PrimePower Cell EM violations?**
 - The first version of Post-APR netlist?
 - The first version of max_tran/cap fixing completed?

Agenda

- Cell EM Introduction
- Cell EM Trend?
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- **Experiment Result**
- N7/N6/N5/N3 Cases Sharing
- Summary

Experiment result – Background & Conclusion

- **Experiment background**

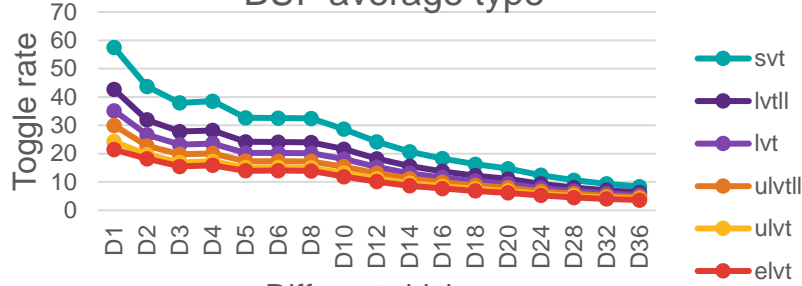
- Toggle rate value is based on the "5*5" in the table
- Checking 4 cell types (BUF, AOI, SDF , MB4)
- Process including N5/N3

- **Experiment conclusion**

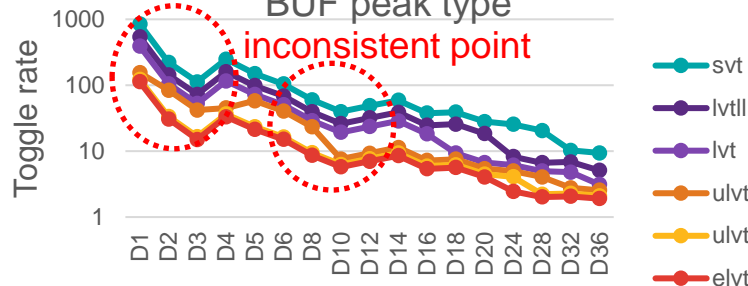
- The lower VT leads worse EM (smaller toggle rate)
- The larger driving cell leads worse EM (smaller toggle rate)
 - Except few cells(peak/rms index), most cells are in the consistent trend
- More advanced process doesn't lead worse EM: no consistent relation.

Experiment result – Cross Cell Type & Driving (N5)

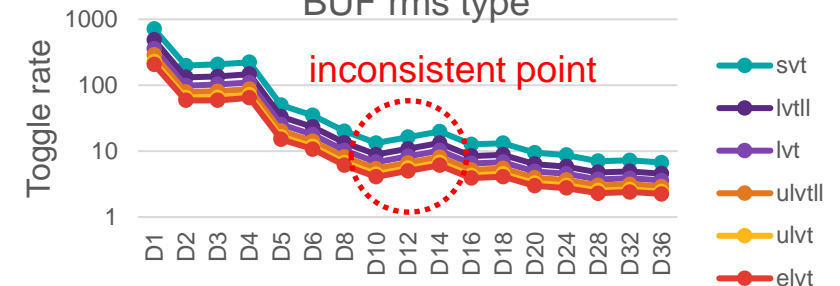
BUF average type



BUF peak type

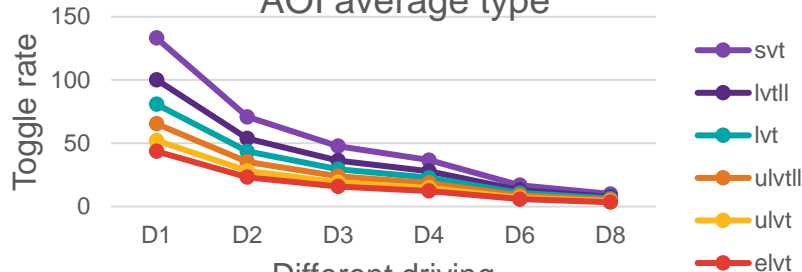


BUF rms type



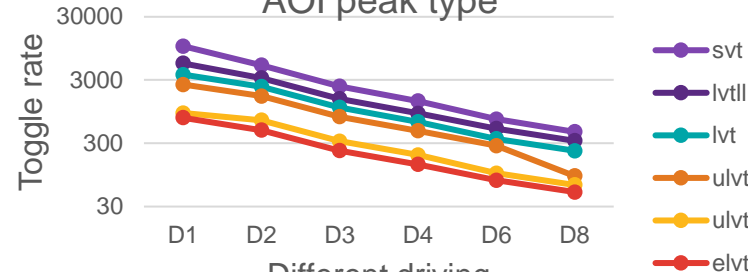
Different driving

AOI average type



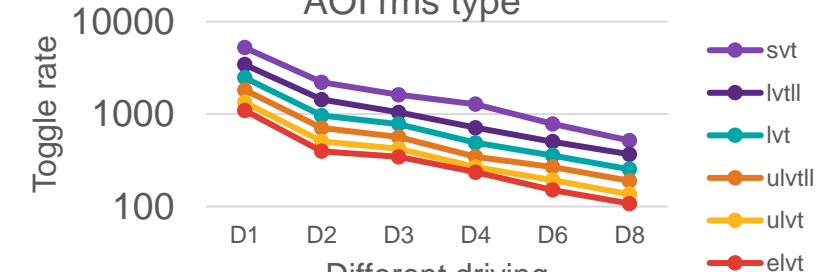
Different driving

AOI peak type



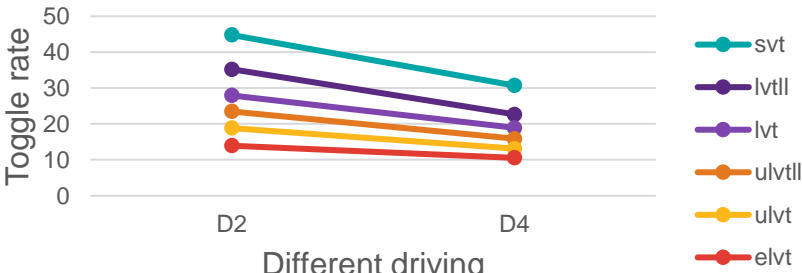
Different driving

AOI rms type



Different driving

SDF average type



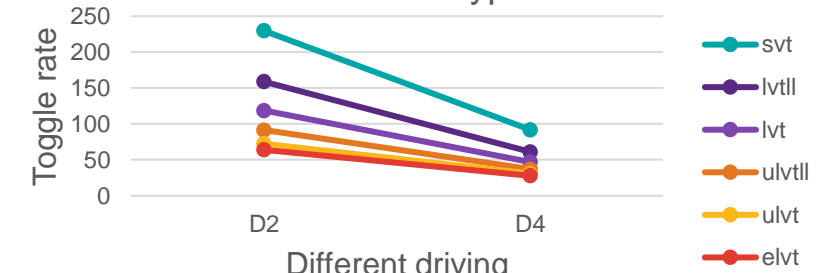
Different driving

SDF peak type



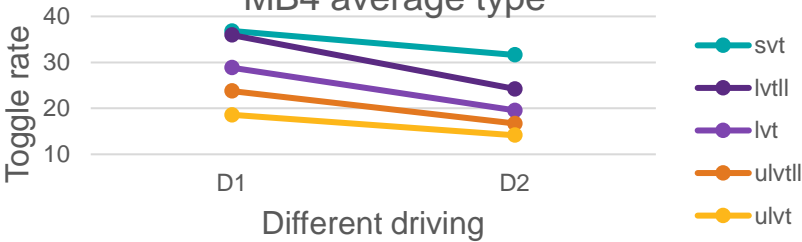
Different driving

SDF rms type



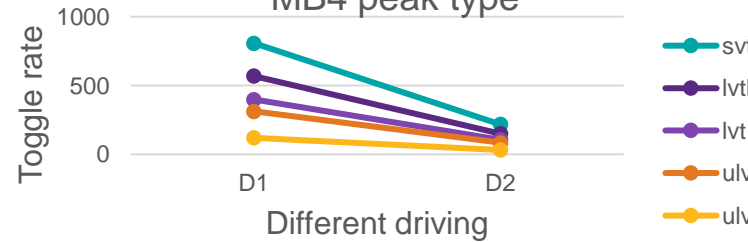
Different driving

MB4 average type



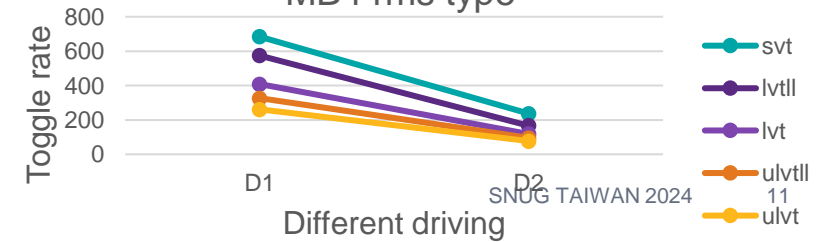
Different driving

MB4 peak type

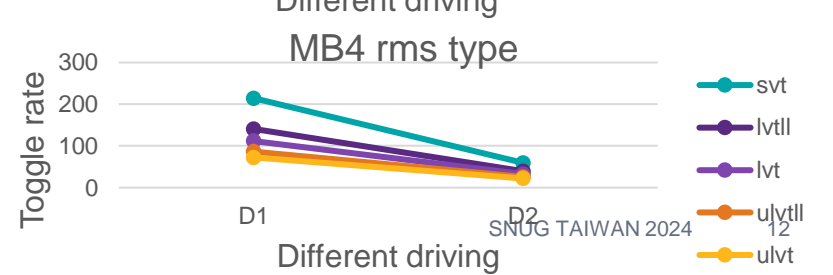
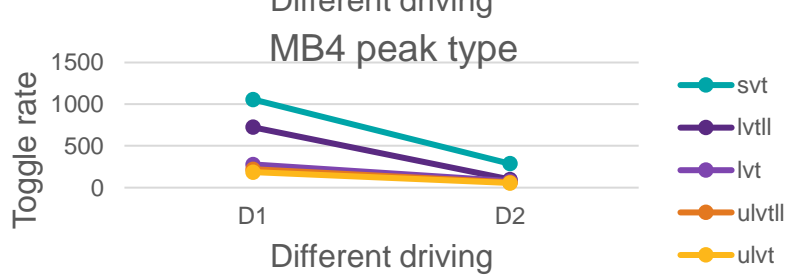
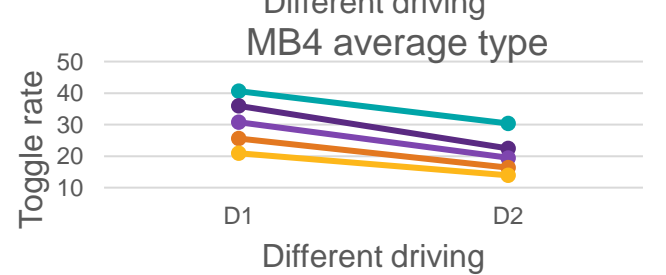
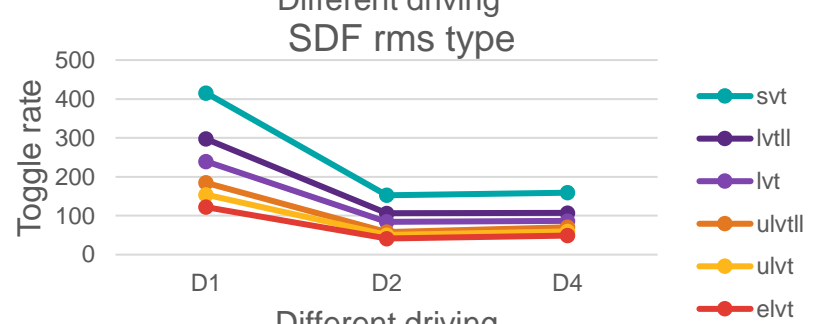
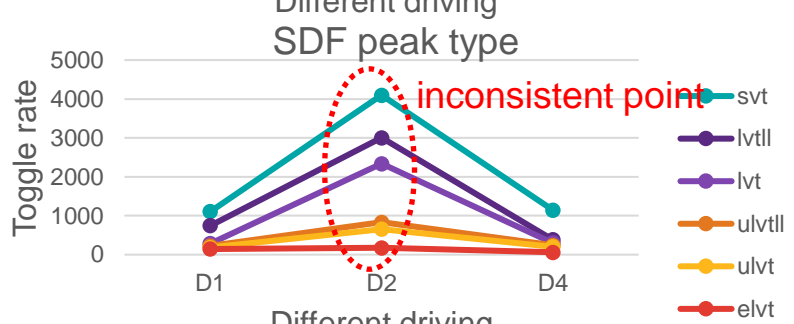
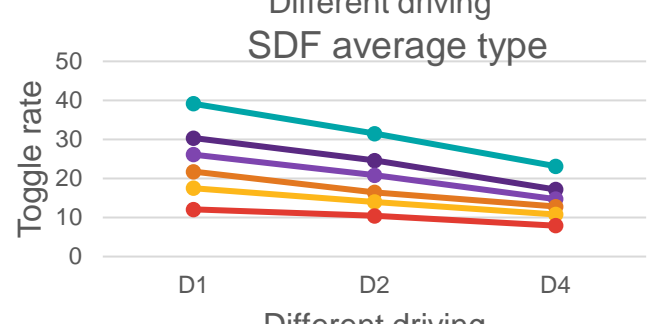
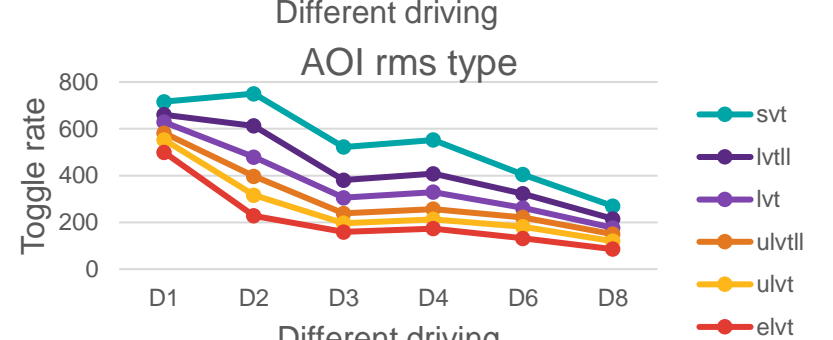
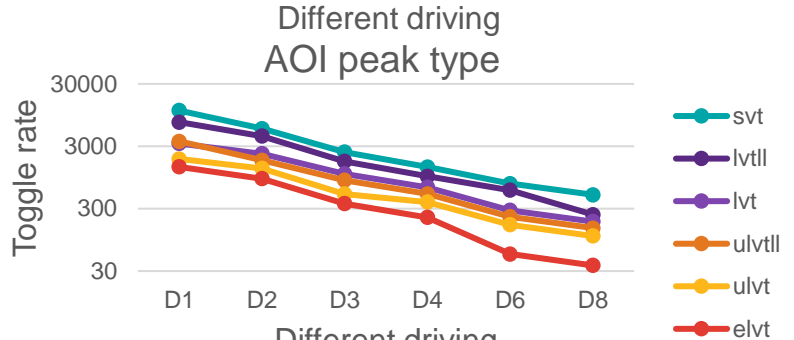
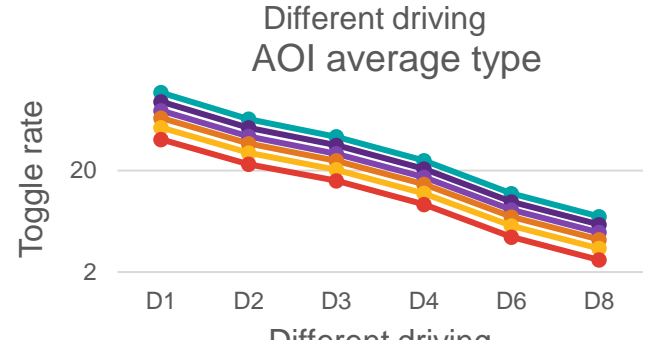
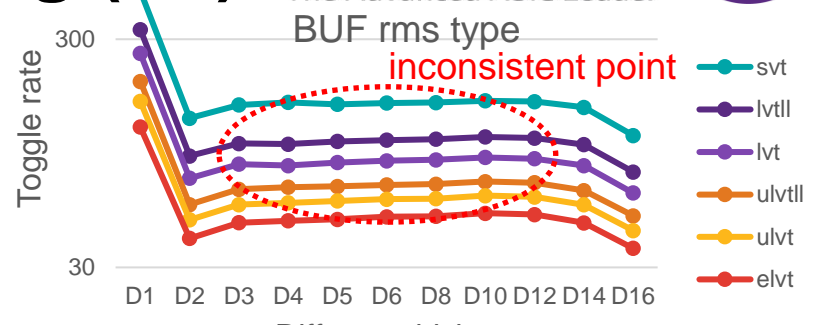
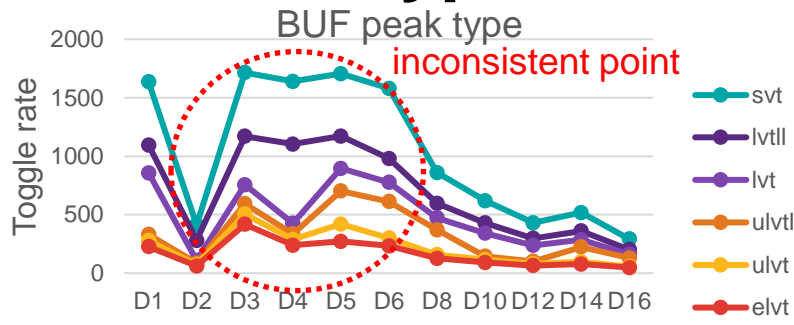
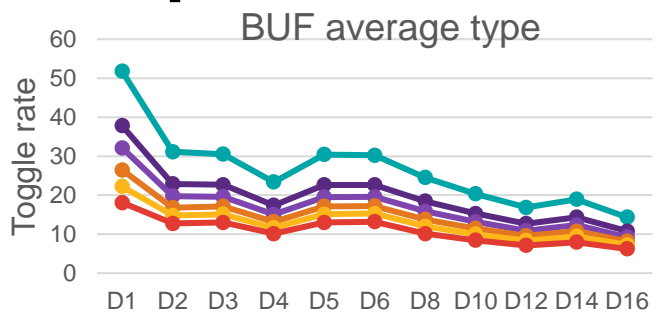


Different driving

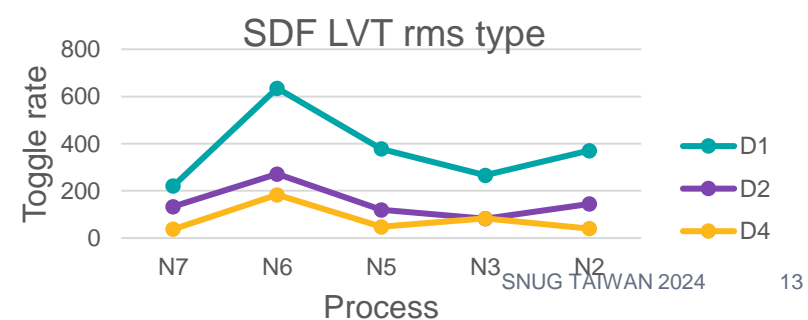
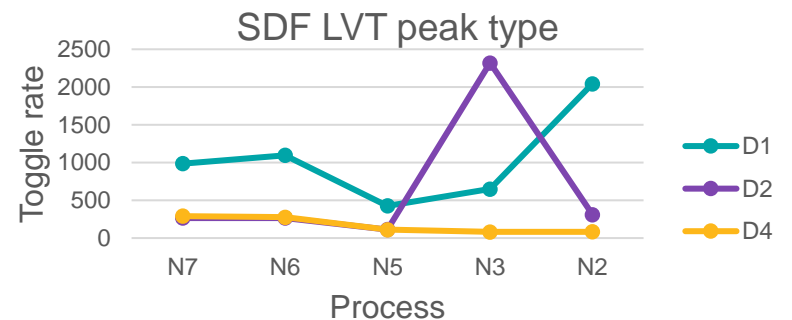
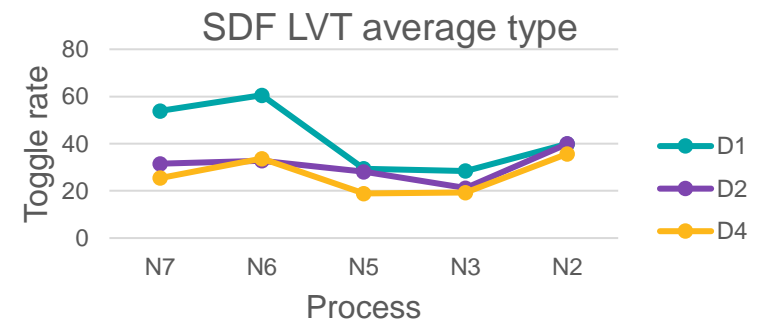
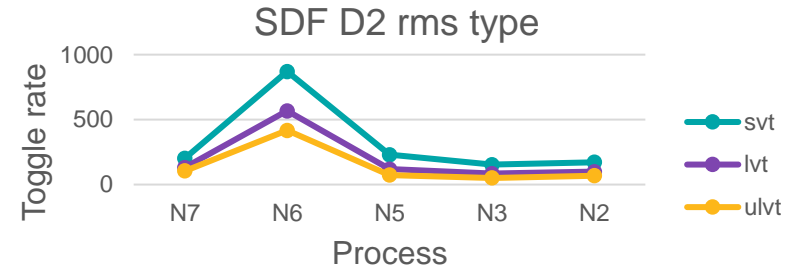
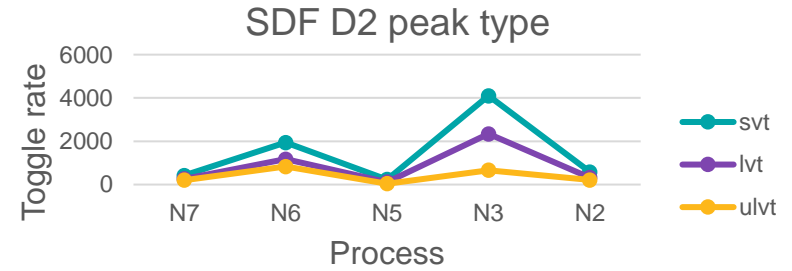
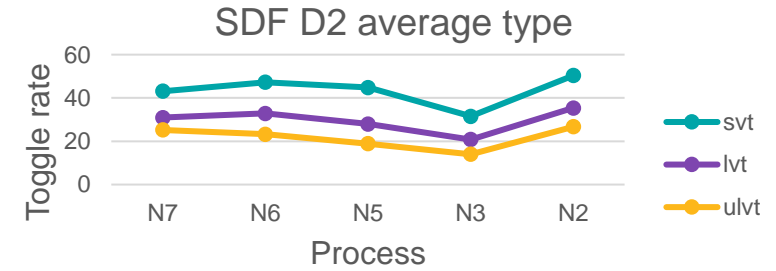
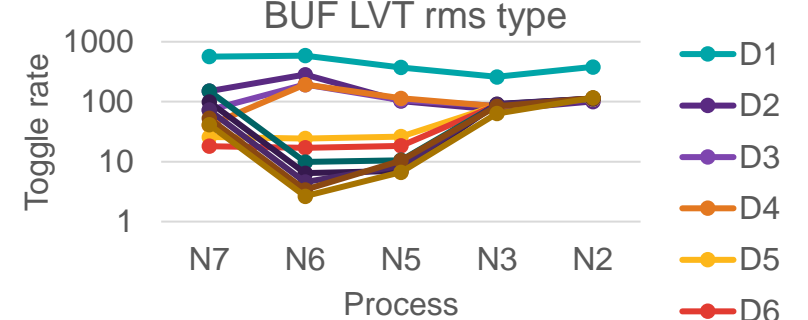
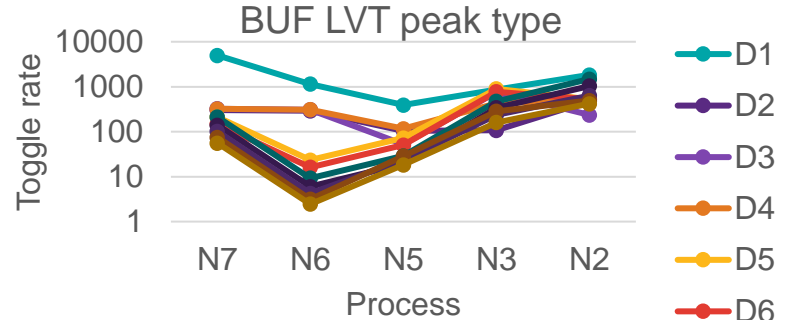
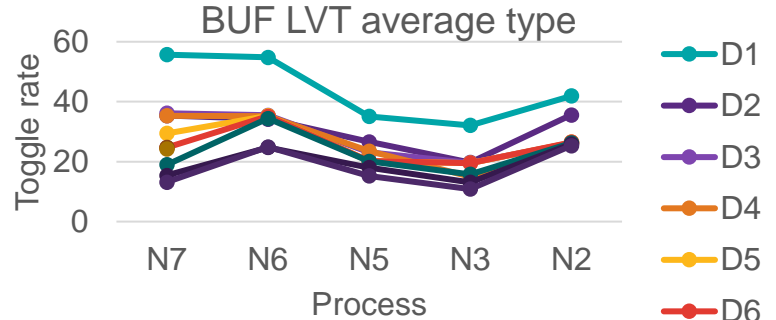
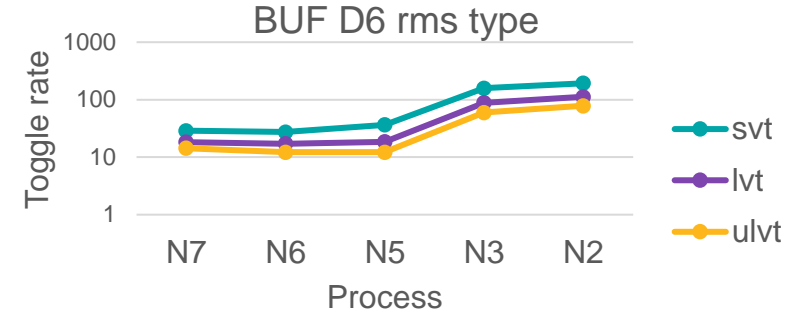
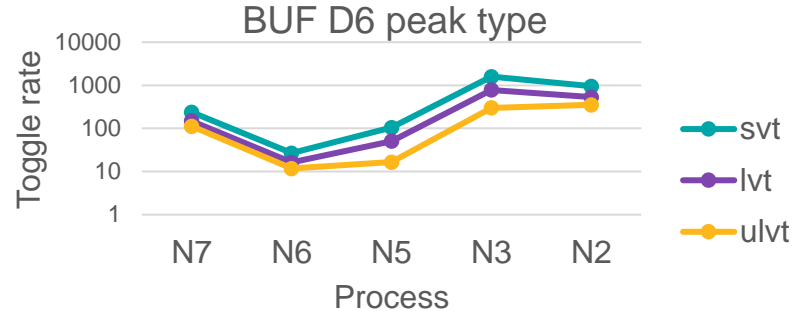
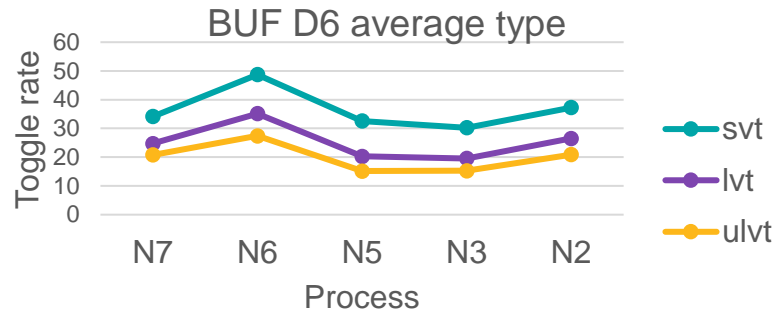
MB4 rms type



Experiment result – Cross Cell Type & Driving (N3)



Experiment result – Cross Process



Agenda

- Cell EM Introduction
- Cell EM Trend?
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- Experiment Result
- **N7/N6/N5/N3 Cases Sharing**
- Summary

Advanced Process Case Sharing

- Suggest to do cell EM analysis after the max_tran/cap fixing
 - Following case results are based on the max_tran/cap fixing completed
- All of the cases don't have cell EM violation even 2GHz speed

Process	Design Info	EM violation number	Run time	Mem usage
N3	Instance count : 2K Clock speed : 2GHz	0	20 secs	2GB
N5	Instance count : 43M Clock speed : 2GHz	0	5.23 hours	84GB
N5	Instance count : 250M Clock speed : 2GHz	0	32.2 hours	520GB
N6	Instance count : 6M Clock speed : 2GHz	0	2.35 hours	45GB
N7	Instance count : 8M Clock speed : 0.5GHz	0	1 hour	20GB

Agenda

- **Cell EM Introduction**
- **Cell EM Trend?**
 - Analyze by Cell EM Library: Cross Cell Type / Driving / Process
 - Analyze by Real Case: Different Process / Design Spec
- **Experiment Result**
- **N7/N6/N5/N3 Cases Sharing**
- **Summary**

Summary

- **PrimePower can analyze the Cell EM violations by library & design spec**
 - Library is the cell EM library. Design spec includes constraint, activity file etc.
- **Experiment to understand the cell EM trend**
 - Analysis by 4 cell type (BUF, AOI, SDF, MB4) @ process N5/N3
 - The lower VT leads worse EM (smaller toggle rate)
 - The larger driving cell leads worse EM (smaller toggle rate)
 - More advanced process doesn't lead worse EM, it's no consistent relation.
- **N7/N6/N5/N3 Cases Sharing**
 - Suggest to do cell EM analysis after the max_tran/cap fixing
 - All of the cases don't have cell EM violation even 2GHz speed

THANK YOU

Our
Technology,
Your
Innovation™